



A schematic diagram of a device structure, likely a quantum device or a sensor. The structure consists of a central rectangular region labeled "Bi" (Bismuth) with a width "C". This central region is flanked by two larger rectangular regions, one on the left and one on the right, both labeled "D". The central region is further divided into three horizontal sections: a top section, a middle section, and a bottom section. The top and bottom sections are labeled "7" and "d" respectively, indicating their thickness. The middle section is labeled "9" and "d", indicating its width and thickness. The central region is also flanked by two circular regions, one on the left and one on the right, both labeled "9", indicating their radius. The central region is also flanked by two rectangular regions, one on the left and one on the right, both labeled "9", indicating their width. The central region is also flanked by two rectangular regions, one on the left and one on the right, both labeled "9", indicating their width. The central region is also flanked by two rectangular regions, one on the left and one on the right, both labeled "9", indicating their width.